

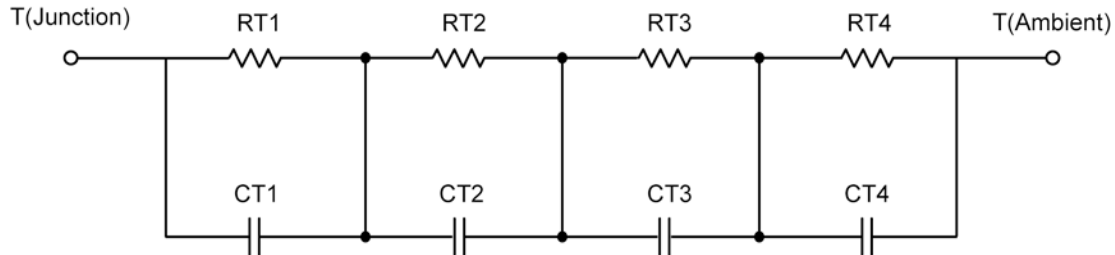
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	9.9521	N/A	3.0072
RT2	2.0391	N/A	5.1086
RT3	50.6042	N/A	11.7426
RT4	22.4046	N/A	1.1416
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	23.5238 m	N/A	37.0279 m
CT2	2.2547 m	N/A	17.9728 m
CT3	1.6397	N/A	119.0820 m
CT4	101.6106 m	N/A	1.4260 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	1.6630	N/A	1.7134
RF2	18.3605	N/A	9.2417
RF3	18.0648	N/A	6.3472
RF4	46.9117	N/A	3.6977
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	1.9063 m	N/A	1.4095 m
CF2	19.6849 m	N/A	11.4318 m
CF3	117.6042 m	N/A	119.4319 m
CF4	1.6582	N/A	16.4462 m

Note

NA indicates not applicable

